DESCRIPTION

The DTD113Z is available in SOT-23 package.

FEATURE

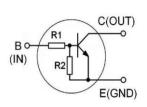
- Built-In Biasing Resistors, $R_1 = 1k\Omega$, $R_2 = 10k\Omega$
- Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors.
- Only the on/off conditions need to be set for operation, making the circuit design easy.

ORDERING INFORMATION

Package Type	Part Number	
SOT-23	DTD113Z	
Note	SPQ: 3,000pcs/Reel	
AiT provides all RoHS Compliant Products		

PIN DESCRIPTION





PIN#	DESCRIPTION	
1	BASE (IN)	
2	EMITTER (GND)	
3	COLLECTOR (OUT)	

ABSOLUTE MAXIMUM RATINGS

 $T_A = 25$ °C, unless otherwise noted.

Vcc, Supply Voltage	50V
V _{IN} , Input Voltage	-5V ~ +10V
I _{OUT} , Output Current	500mA
P _D , Power Dissipation	200mW
T _J , Junction Temperature	150°C
T _{STG} , Storage Temperature	-55°C~+150°C

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

 T_A = 25°C, unless otherwise noted.

Parameter	Symbol	Conditions	Min	Тур.	Max	Unit
Input Voltage	V _{IN(OFF)}	V _{CC} = 5V, I _O =100μA	-	-	0.3	
	V _{IN(ON)}	V ₀ =0.3V, I ₀ =20mA	1.5	-	-	V
Output Voltage	V _{OUT(ON)}	I _{OUT} = 50mA, I _{IN} = 2.5mA	-	0.1	0.3	V
Input Current	II	V _{IN} = 5V	-	-	7.2	mA
Collector Cut-Off Current	I _{OUT(off)}	V _{CC} =50V, V _I = 0	-	-	0.5	μΑ
DC Current Gain	h _{FE}	V _{OUT} = 5V, I _{OUT} = 50mA	82	-	-	-
Transition Frequency	f⊤	V _{CE} = 10V, I _E = 50mA, f=100MHz	-	200	-	MHz
Input Resistance	R ₁	-	0.7	1	1.3	ΚΩ
Resistance Ratio	R ₁ /R ₂	-	8	10	12	-

TYPICAL PERFORMANCE CHARACTERISTICS

Fig 1. ON Characteristic

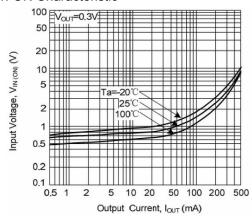


Fig 3. Output Voltage vs. Output Current

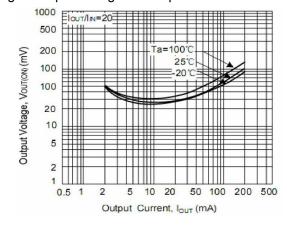


Fig 2. DC Current Gain

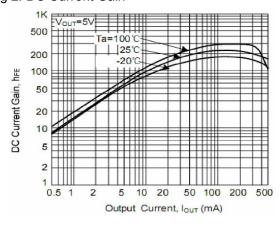
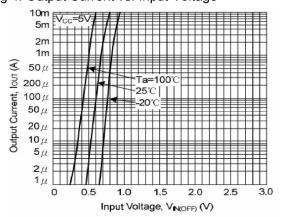
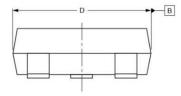


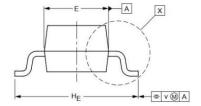
Fig 4. Output Current vs. Input Voltage

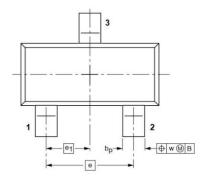


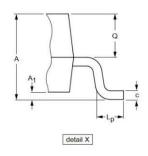
PACKAGE INFORMATION

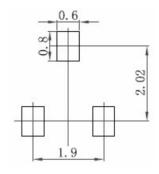
Dimension in SOT-23 Package (Unit: mm)











The recommended mounting pad size

SYMBOL	MIN MAX			
Α	0.900	1.150		
A1	0.100			
bp	0.380	0.480		
С	0.090	0.150		
D	2.800	3.000		
E	1.200	1.400		
Е	1.900			
E1	0.950			
HE	2.100	2.550		
Lp	0.150	0.450		
Q	0.450	0.550		
V	0.200			
W	0.100			

DTD113Z

SWITCHING TRANSISTOR 500mA NPN DIGITAL TRANSISTOR

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